SLRS022A - DECEMBER 1976 - REVISED OCTOBER 1995

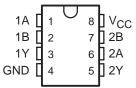
#### PERIPHERAL DRIVERS FOR HIGH-VOLTAGE, HIGH-CURRENT DRIVER APPLICATIONS

- Characterized for Use to 300 mA
- High-Voltage Outputs
- No Output Latch-Up at 30 V (After Conducting 300 mA)
- Medium-Speed Switching
- Circuit Flexibility for Varied Applications and Choice of Logic Function
- TTL-Compatible Diode-Clamped Inputs
- Standard Supply Voltages
- Plastic DIP (P) With Copper Lead Frame for Cooler Operation and Improved Reliability
- Package Options Include Plastic Small Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

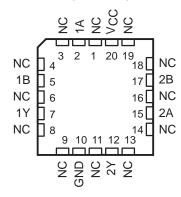
#### **SUMMARY OF SERIES 55461/75461**

DEVICE	LOGIC	PACKAGES
SN55461	AND	FK, JG
SN55462	NAND	FK, JG
SN55463	OR	FK, JG
SN75461	AND	D, P
SN75462	NAND	D, P
SN75463	OR	D, P

#### SN55461, SN55462, SN55463 . . . JG PACKAGE SN75461, SN75462, SN75463 . . . D OR P PACKAGE (TOP VIEW)



SN55461, SN55462, SN55463 . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

#### description

These dual peripheral drivers are functionally interchangeable with SN55451B through SN55453B and SN75451B through SN75453B peripheral drivers, but are designed for use in systems that require higher breakdown voltages than those devices can provide at the expense of slightly slower switching speeds. Typical applications include logic buffers, power drivers, relay drivers, lamp drivers, MOS drivers, line drivers, and memory drivers.

The SN55461/SN75461, SN55462/SN75462, and SN55463/SN75463 are dual peripheral AND, NAND, and OR drivers respectively (assuming positive logic), with the output of the gates internally connected to the bases of the npn output transistors.

Series SN55461 drivers are characterized for operation over the full military temperature range of -55°C to 125°C. Series SN75461 drivers are characterized for operation from 0°C to 70°C.

## SN55461 THRU SN55463 SN75461 THRU SN75463 DUAL PERIPHERAL DRIVERS

SLRS022A - DECEMBER 1976 - REVISED OCTOBER 1995

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

		SN55'	SN75'	UNIT	
Supply voltage, V <sub>CC</sub> (see Note 1)		7	7	V	
Input voltage, V <sub>I</sub>		5.5	5.5	V	
Intermitter voltage (see Note 2)		5.5	5.5	V	
Off-state output voltage, VO	35	35	V		
Continuous collector or output current (see Note 3)	400	400	mA		
Peak collector or output current ( $t_W \le 10$ ms, duty cycle $\le 50\%$ , see No.	ote 4)	500	500	mA	
Continuous total power dissipation		See Diss	See Dissipation Rating Table		
Operating free-air temperature range, TA		-55 to 125	0 to 70	°C	
Storage temperature range, T <sub>Stg</sub>		-65 to 150	-65 to 150	°C	
Case temperature for 60 seconds, T <sub>C</sub>	FK package 260			°C	
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	JG package	300		°C	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D or P package		260	°C	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. Voltage values are with respect to network GND unless otherwise specified.

- 2. This is the voltage between two emitters A and B.
- 3. This value applies when the base-emitter resistance (RBE) is equal to or less than 500  $\Omega$ .
- 4. Both halves of these dual circuits may conduct rated current simultaneously; however, power dissipation averaged over a short time interval must fall within the continuous dissipation rating.

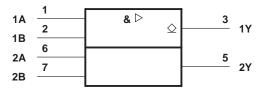
#### **DISSIPATION RATING TABLE**

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING	T <sub>A</sub> = 125°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	-
FK	1375 mW	11.0 mW/°C	880 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	210 mW
Р	1000 mW	8.0 mW/°C	640 mW	-

#### recommended operating conditions

	SN55'			SN75'			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	UNII
Supply voltage, V <sub>CC</sub>	4.5	5	5.5	4.75	5	5.25	V
High-level input voltage, V <sub>IH</sub>	2			2			V
Low-level input voltage, V <sub>IL</sub>			0.8			0.8	V
Operating free-air temperature, TA	-55		125	0		70	°C

## logic symbol†



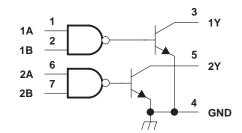
<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for D, JG, and P packages.

# FUNCTION TABLE (each driver)

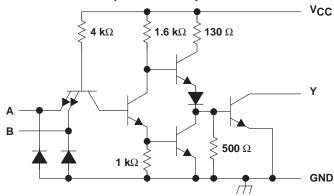
Α	В	Y
L	L	L (on state)
L	Н	L (on state)
Н	L	L (on state)
Н	Н	H (off state)

positive logic:  $\underline{\underline{\phantom{A}}}$  Y = AB or  $\overline{A}$  +  $\overline{B}$ 

## logic diagram (positive logic)



#### schematic (each driver)



Resistor values shown are nominal.

#### electrical characteristics over recommended operating free-air temperature range

	DADAMETED	TEGT 001	DITIONIST	0,	SN55461		SN75461			LINUT
	PARAMETER	TEST CONDITIONS†		MIN	TYP‡	MAX	MIN	TYP <sup>‡</sup>	MAX	UNIT
VIK	Input clamp voltage	$V_{CC} = MIN,$	$I_I = -12 \text{ mA}$		-1.2	-1.5		-1.2	-1.5	V
ІОН	High-level output current	$V_{CC} = MIN,$ $V_{OH} = 35 V$	V <sub>IH</sub> = MIN,			300			100	μΑ
V	Low-level output voltage	$V_{CC} = MIN,$ $I_{OL} = 100 \text{ mA}$			0.25	0.5		0.25	0.4	V
VOL		V <sub>CC</sub> = MIN, I <sub>OL</sub> = 300 mA			0.5	0.8		0.5	0.7	V
IĮ	Input current at maximum input voltage	$V_{CC} = MAX$ ,	V <sub>I</sub> = 5.5 V			1			1	mA
ΊΗ	High-level input current	$V_{CC} = MAX$ ,	V <sub>I</sub> = 2.4 V			40			40	μΑ
I <sub>I</sub> L	Low-level input current	$V_{CC} = MAX$ ,	V <sub>I</sub> = 0.4 V		-1	-1.6		-1	-1.6	mA
ICCH	Supply current, outputs high	$V_{CC} = MAX$ ,	V <sub>I</sub> = 5 V		8	11		8	11	mA
ICCL	Supply current, outputs low	$V_{CC} = MAX$ ,	V <sub>I</sub> = 0		56	76		56	76	mA

For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

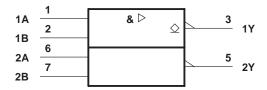
# switching characteristics, $V_{CC}$ = 5 V, $T_A$ = 25°C

	PARAMETER			TEST CONDITIONS			MAX	UNIT
<sup>t</sup> PLH	Propagation delay time, low-to-high-level o	utput				30	55	
tPHL	PHL Propagation delay time, high-to-low-level output		I <sub>O</sub> ≈ 200 mA,	$C_{L} = 15 \text{ pF},$		25	40	
tTLH			$R_L = 50 \Omega$ ,	See Figure 1		8	20	ns
tTHL	Transition time, high-to-low-level output	ansition time, high-to-low-level output				10	20	
V	/ Literature of control of the contr	SN55461	V <sub>S</sub> = 30 V,	I <sub>O</sub> ≈ 300 mA,		V <sub>S</sub> -10		mV
VOH	High-level output voltage after switching	SN75461	See Figure 2		V <sub>S</sub> -10			IIIV



<sup>‡</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

## logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

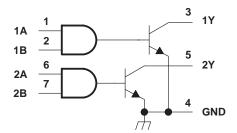
Pin numbers shown are for D, JG, and P packages.

# FUNCTION TABLE (each driver)

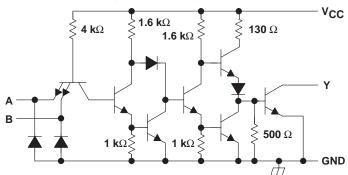
Α	В	Y
L	L	H (off state)
L	Н	H (off state)
Н	L	H (off state)
Н	Н	L (on state)

positive logic:  $\underline{\quad Y = AB \text{ or } A + B}$ 

## logic diagram (positive logic)



## schematic (each driver)



Resistor values shown are nominal.

#### electrical characteristics over recommended operating free-air temperature range

	24244555		t		SN55462		SN75462			
	PARAMETER	TEST CONDITIONS†		MIN	TYP‡	MAX	MIN	TYP‡	MAX	UNIT
٧IK	Input clamp voltage	$V_{CC} = MIN,$	$I_I = -12 \text{ mA}$		-1.2	-1.5		-1.2	-1.5	V
ЮН	High-level output current	V <sub>CC</sub> = MIN, V <sub>OH</sub> = 35 V	V <sub>IL</sub> = 0.8 V,			300			100	μΑ
.,	Low-level output voltage	V <sub>CC</sub> = MIN, I <sub>OL</sub> = 100 mA			0.25	0.5		0.25	0.4	.,
VOL		V <sub>CC</sub> = MIN, I <sub>OL</sub> = 300 mA			0.5	0.8		0.5	0.7	V
l <sub>l</sub>	Input current at maximum input voltage	$V_{CC} = MAX$ ,	V <sub>I</sub> = 5.5 V			1			1	mA
lн	High-level input current	$V_{CC} = MAX$ ,	V <sub>I</sub> = 2.4 V			40			40	μΑ
I <sub>IL</sub>	Low-level input current	$V_{CC} = MAX$ ,	V <sub>I</sub> = 0.4 V		-1.1	-1.6		-1.1	-1.6	mA
ІССН	Supply current, outputs high	$V_{CC} = MAX,$	V <sub>I</sub> = 0		13	17		13	17	mA
ICCL	Supply current, outputs low	$V_{CC} = MAX$ ,	V <sub>I</sub> = 5 V		61	76		61	76	mA

For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

## switching characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

	PARAMETER			TEST CONDITIONS			MAX	UNIT
tPLH	Propagation delay time, low-to-high-level of	utput				45	65	
tPHL				$C_L = 15 pF$ ,		30	50	
tTLH				See Figure 1		13	25	ns
tTHL	THL Transition time, high-to-low-level output					10	20	
V	/ High level cutout valtage after suitables	SN55462	$V_S = 30 \text{ V},$	I <sub>O</sub> ≈ 300 mA,		V <sub>S</sub> -10		mV
V <sub>OH</sub> H	High-level output voltage after switching	SN75462	See Figure 2		V <sub>S</sub> -10			IIIV



<sup>‡</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

## logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

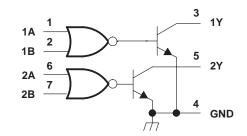
Pin numbers shown are for D, JG, and P packages.

# FUNCTION TABLE (each driver)

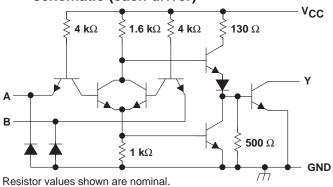
Α	В	Y
L	L	L (on state)
L	Н	H (off state)
Н	L	H (off state)
Н	Н	H (off state)

positive logic:  $Y = A + B \text{ or } \overline{A} \overline{B}$ 

## logic diagram (positive logic)



## schematic (each driver)



## electrical characteristics over recommended operating free-air temperature range

	DADAMETED	TEOT 001	IDITIONST	• •	SN55463		SN75463			UNIT
	PARAMETER	IESI CON	TEST CONDITIONS†		TYP‡	MAX	MIN	TYP‡	MAX	UNII
VIK	Input clamp voltage	$V_{CC} = MIN,$	$I_I = -12 \text{ mA}$		-1.2	-1.5		-1.2	-1.5	V
ЮН	High-level output current	V <sub>CC</sub> = MIN, V <sub>OH</sub> = 35 V	V <sub>IH</sub> = MIN,			300			100	μΑ
V	Low-level output voltage	V <sub>CC</sub> = MIN, I <sub>OL</sub> = 100 mA			0.25	0.5		0.25	0.4	V
VOL		$V_{CC} = MIN,$ $I_{OL} = 300 \text{ mA}$			0.5	0.8		0.5	0.7	V
II	Input current at maximum input voltage	$V_{CC} = MAX$ ,	V <sub>I</sub> = 5.5 V			1			1	mA
ΙН	High-level input current	$V_{CC} = MAX$ ,	V <sub>I</sub> = 2.4 V			40			40	μΑ
IլL	Low-level input current	$V_{CC} = MAX$ ,	V <sub>I</sub> = 0.4 V		-1	-1.6		-1	-1.6	mA
ICCH	Supply current, outputs high	$V_{CC} = MAX$ ,	V <sub>I</sub> = 5 V		8	11		8	11	mA
ICCL	Supply current, outputs low	$V_{CC} = MAX$ ,	V <sub>I</sub> = 0		58	76		58	76	mA

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

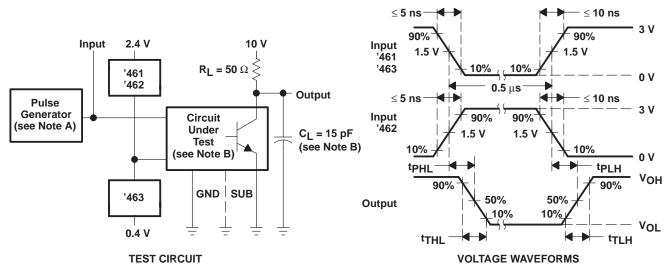
## switching characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

	PARAMETER		TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
tPLH	Propagation delay time, low-to-high-level of				30	55		
tPHL	Propagation delay time, high-to-low-level o	I <sub>O</sub> ≈ 200 mA,	C <sub>L</sub> = 15 pF, See Figure 1		25	40		
tTLH	Transition time, low-to-high-level output	$R_L = 50 \Omega$ ,			8	25	ns	
tTHL	Transition time, high-to-low-level output				10	25	İ	
V	High level cutout valtage ofter cuitaking	SN55463	V <sub>S</sub> = 30 V,	l <sub>O</sub> ≈ 300 mA,		V <sub>S</sub> -10		mV
VOH	High-level output voltage after switching	SN75463	See Figure 2	-	V <sub>S</sub> -10			1117



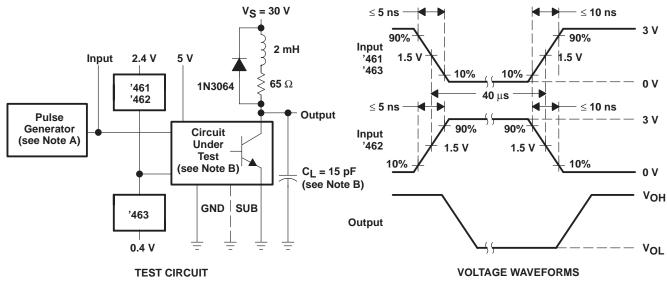
<sup>‡</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

#### PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The pulse generator has the following characteristics: PRR  $\leq$  1 MHz,  $Z_O\approx50~\Omega$ 
  - B. C<sub>L</sub> includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms for Switching Times



- NOTES: A. The pulse generator has the following characteristics: PRR  $\leq$  12.5 kHz, Z<sub>O</sub> = 50  $\Omega$ .
  - B. C<sub>L</sub> includes probe and jig capacitance.

Figure 2. Test Circuit and Voltage Waveforms for Latch-Up Test







10-Jun-2014

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
JM38510/12908BPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510 /12908BPA	Samples
JM38510/12909BPA	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI	-55 to 125		
M38510/12908BPA	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510 /12908BPA	Samples
SN55461JG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI	-55 to 125		
SN55462JG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI	-55 to 125		
SN55463JG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI	-55 to 125		
SN75461D	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI			
SN75461P	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI			
SN75462D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75462	Samples
SN75462DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	75462	Samples
SN75462P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75462P	Samples
SN75462PE4	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75462P	Samples
SN75463D	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	0 to 70		
SN75463DR	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	0 to 70		
SN75463P	ACTIVE	PDIP	Р	8	50	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75463P	Samples
SNJ55461FK	OBSOLETE	LCCC	FK	20		TBD	Call TI	Call TI	-55 to 125		
SNJ55461JG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI	-55 to 125		
SNJ55462FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	SNJ55 462FK	Sample
SNJ55462JG	ACTIVE	CDIP	JG	8	1	TBD	A42	N / A for Pkg Type	-55 to 125	SNJ55462JG	Samples
SNJ55463JG	OBSOLETE	CDIP	JG	8		TBD	Call TI	Call TI	-55 to 125		

<sup>(1)</sup> The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

### PACKAGE OPTION ADDENDUM



10-Jun-2014

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN55461, SN55462, SN55463, SN75461, SN75462, SN75463:

Catalog: SN75461, SN75462, SN75463

Military: SN55461, SN55462, SN55463

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product



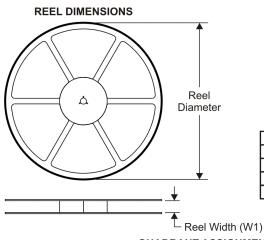


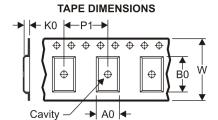
10-Jun-2014

• Military - QML certified for Military and Defense Applications



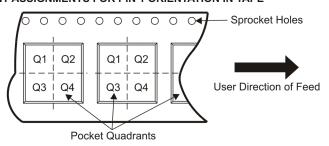
#### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
	Overall width of the carrier tape
P1	Pitch between successive cavity centers

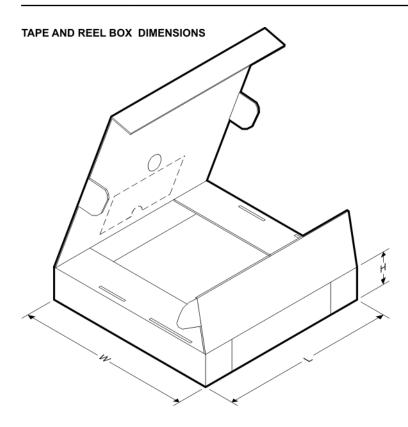
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75462DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1



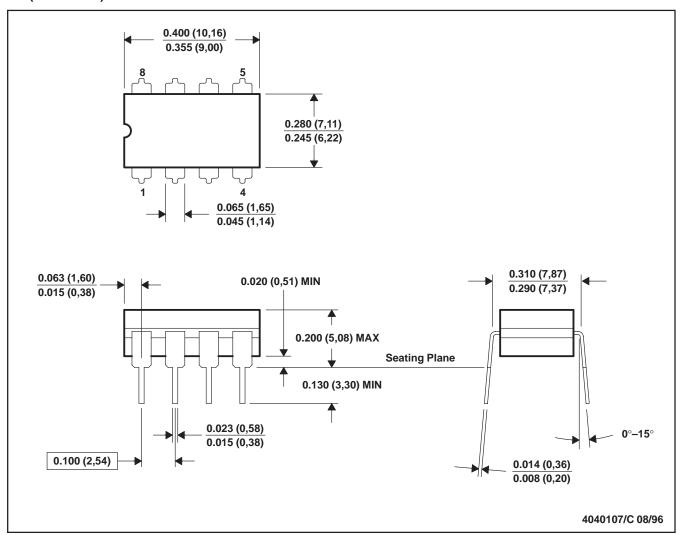


#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN75462DR	SOIC	D	8	2500	340.5	338.1	20.6	

## JG (R-GDIP-T8)

#### **CERAMIC DUAL-IN-LINE**



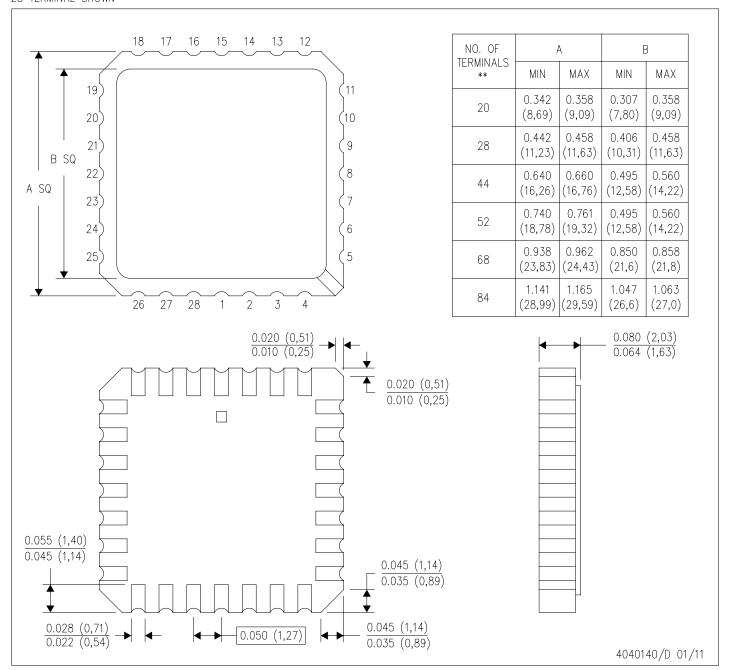
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification.
- E. Falls within MIL STD 1835 GDIP1-T8

## FK (S-CQCC-N\*\*)

## LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN

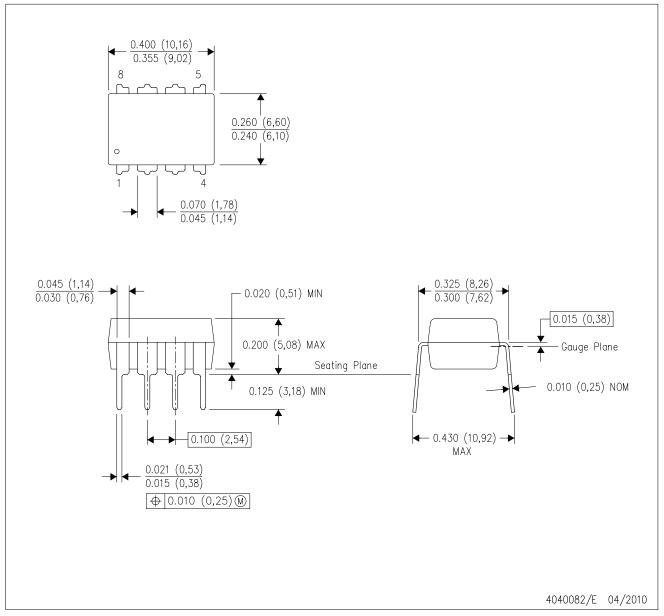


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



# P (R-PDIP-T8)

## PLASTIC DUAL-IN-LINE PACKAGE

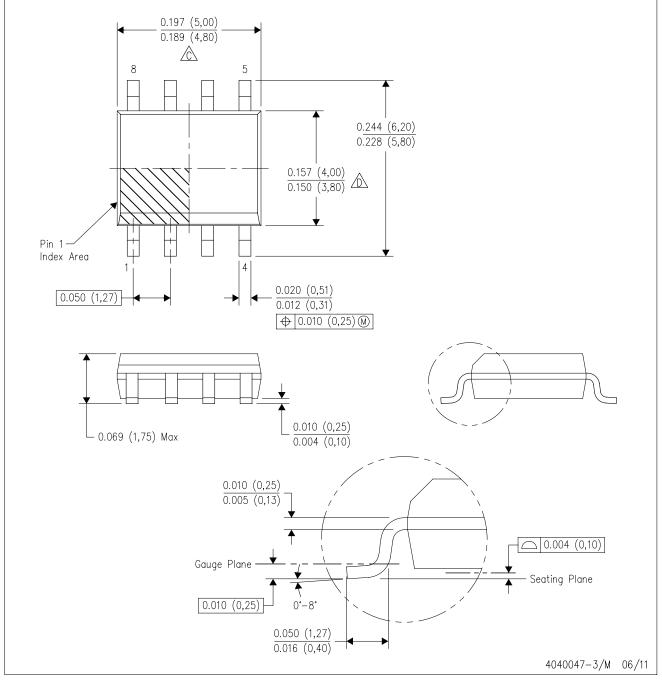


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



## D (R-PDSO-G8)

## PLASTIC SMALL OUTLINE

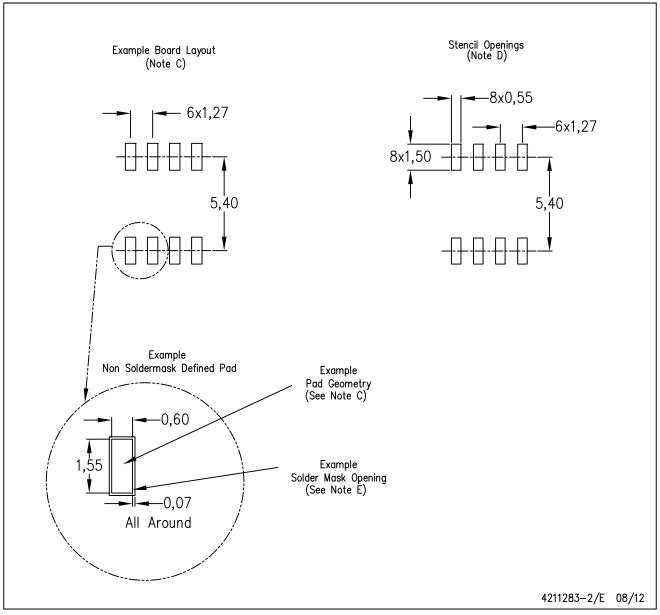


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



# D (R-PDSO-G8)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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